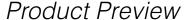
Precision Operational Amplifier, 10 μV, Zero-Drift, 1.6 V to 5.5 V Supply, 1.5 MHz



NCS21801, NCS21802, NCS21803, NCS21804

The NCS21801, NCS21802, NCS21803, and NCS21804 are precision op amps featuring low input offset voltage and low offset drift over time and temperature. The common mode voltage range extends 100 mV beyond the supply rails, which makes it suitable for both high-side and low-side current sensing applications.

The NCS2180x is available in single, dual, and quad channel configurations. All versions are specified for operation from -40°C to +125°C. NCV prefix parts are automotive grade 1 qualified and offer performance over the extended temperature range from -40°C to +150°C.

Features

- Input Offset Voltage: ±10 μV max
- Offset Voltage Drift Over Temperature: 5 nV/°C
- \bullet Common Mode Input Voltage Range: $V_{SS} 0.1 \text{ V}$ to $V_{DD} + 0.1 \text{ V}$
- Supply Voltage Range: 1.8 V to 5.5 V
- Extended Supply Voltage Range: 1.6 V to 5.5 V for $T_A = 0^{\circ}$ C to 85° C
- Unity Gain Bandwidth: 1.5 MHz
- Quiescent Consumption: 95 μA max
- Enable Function available on NCS21803
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- High-Side Current Sensing
- Low-Side Current Sensing
- Difference Amplifier
- Instrumentation Amplifier
- Power Management
- Automotive

This document contains information on a product under development. ON Semiconductor reserves the right to change or discontinue this product without notice.



ON Semiconductor®

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SC-88A / SC70-5 CASE 419A-02



TSOP-5 CASE 483



SC-88 / SC70-6 CASE 419B-02



UDFN8 CASE 517AW



Micro8 CASE 846A-02



TSSOP-14 WB CASE 948G

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 2 of this data sheet.

PIN CONNECTIONS

See pin connections on page 3 of this data sheet.

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet

DEVICE MARKING INFORMATION



TSOP-5 CASE 483



SC-88A / SC70-5 CASE 419A-02



SC-88 / SC70-6 / SOT-363 CASE 419B-02



UDFN8, 2x2, 0.5P CASE 517AW



Micro8 CASE 846A-02



TSSOP-14 WB CASE 948G

XX = Specific Device Code A = Assembly Location

Y = Year
W = Work Week
M = Date Code
G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

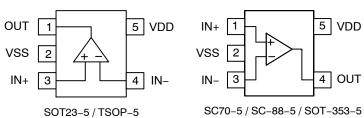
ORDERING INFORMATION

Channels	Enable	Package	Part Number	Marking	Shipping
Industrial and	Consumer				
Single	No	SOT23-5 / TSOP-5	NCS21801		
		SC70-5 / SC-88-5 / SOT-353-5	NCS21801		3000 / Tape & Reel
	Yes	SC-88 / SC70-6 / SOT-363	NCS21803		1
Dual	No	UDFN-8	NCS21802MUTBG		3000 / Tape & Reel
		Micro8	NCS21802DMR2G		4000 / Tape & Reel
Quad	No	TSSOP-14	NCS21804		2500 / Tape & Reel
Automotive Qu	ualified				•
Single	No	SOT23-5 / TSOP-5	NCV21801		2000 / T
		SC70-5 / SC-88-5 / SOT-353-5	NCV21801		3000 / Tape & Reel
Dual	No	Micro8	NCV21802DMR2G		4000 / Tape & Reel
Quad	No	TSSOP-14	NCV21804		2500 / Tape & Reel

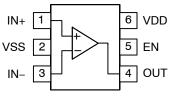
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PIN CONNECTIONS

Single Channel Configuration NCS21801

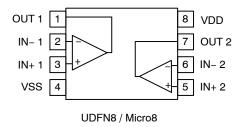


Single Channel with Enable Configuration NCS21803

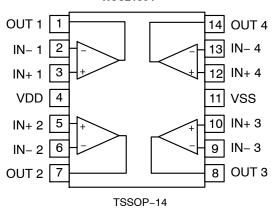


SC88 / SC70-6 / SOT-363

Dual Channel Configuration NCS21802



Quad Channel Configuration NCS21804



MAXIMUM RATINGS

Parameter	Symbol	Rating	Unit
Supply Voltage (Note 1)	V _S	-0.3 to 6	V
Input Voltage	$V_{IN+,}V_{IN-,}V_{EN}$	(V _{SS} – 0.3) to (V _{DD} + 0.3)	V
Differential Input Voltage	$V_{\mathrm{IN+,}}V_{\mathrm{IN-}}$	$\pm (V_{DD} - V_{SS} + 0.3)$	V
Output Voltage (Note 2)	V _{OUT}	(V _{SS} – 0.3) to (V _{DD} + 0.3)	V
Output Short Circuit Current (Note 3)	lout	Continuous	
Input Current into Any Pin (Note 2)	I _{IN}	±10	mA
Maximum Junction Temperature	T _{J(max)}	+150	°C
Storage Temperature Range	T _{STG}	-65 to +150	°C
ESD Human Body Model (Note 3)	НВМ	±2000	V
Charged Device Model (Note 3)	CDM	±1000	V
Latch-up Current (Note 4)		100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Refer to ELECTRICAL CHĂRACTERISTICS, RECOMMENDED OPERATING RANGES and/or APPLICATION INFORMATION for safe operating parameters
- 2. Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5 V beyond the supply rails should be current limited to 10 mA or less
- 3. Short circuit current to ground.
- 4. This device series incorporates ESD protection and is tested by the following methods: ESD Human Body Model tested per JEDEC standard JS-001-2017 (AEC-Q100-002) ESD Charged Device Model tested per JEDEC standard JS-002-2014 (AEC-Q100-011)
- 5. Latch-up Current tested per JEDEC standard: JESD78E.

THERMAL CHARACTERISTICS

Parameter	Symbol	Package	Value	Unit
Thermal Resistance,	θ_{JA}	TSOP-5 / SOT23-5	TBD	°C/W
Junction-to-Air (Notes 6, 7)		SC70-5 / SC-88-5 / SOT-353-5	TBD	
		SC-88 / SC70-6 / SOT-363	TBD	
		UDFN8	TBD	
		Micro8 / MSOP-8	TBD	
		TSSOP-14	TBD	

- 6. Refer to ELECTRICAL CHARACTERISTICS, RECOMMENDED OPERATING RANGES and/or APPLICATION INFORMATION for safe operating parameters
- 7. Values based on copper area of 645 mm² (or 1 in²) of 1 oz copper thickness and FR4 PCB substrate

RECOMMENDED OPERATING RANGES

Parameter	Symbol	Conditions	Min	Max	Unit
Ambient Temperature	T _A	T _A NCS prefix		125	°C
		NCV prefix	-40	150	
Common Mode Input Voltage	V _{CM}	Full temperature range	V _{SS} - 0.1	V _{DD} + 0.1	V
Supply Voltage	V _S T _A = 0 to 85°C		1.6	5.5	V
		Full temperature range	1.8	5.5	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

ELECTRICAL CHARACTERISTICS

At $T_A = +25^{\circ}C$, $V_S = 3.3$ V, and $V_{CM} = V_{OUT} = mid$ -supply, unless otherwise noted. **Boldface** limits apply over the specified temperature range, unless otherwise noted, guaranteed by characterization and/or design.

Parameter	Symbol	Conditions	Temp (°C)	Min	Тур	Max	Unit
Input	•				•	•	•
Common Mode Rejection	CMRR	$V_{CM} = V_{SS} - 0.1$ to V_{DD}	25	113	TBD		dB
Ratio		+ 0.1	-40 to 125	110			1
			-40 to 150	90			1
Input Offset Voltage	V _{OS}		25			±10	μV
Input Offset Voltage Drift	dV _{OS} /dT		-40 to 125		±5	±50	nV/°C
vs. Temperature			-40 to 150		±5	±75	1
Input Bias Current	I _{IB}		25		TBD	±160	pА
			-40 to 125			±600]
			-40 to 150			±4000	1
Input Offset Current	los		25		±5	±160	pА
			-40 to 125			±600	
			-40 to 150			±4000	
Input Capacitance	C _{IN}	Differential	25		1		pF
		Common mode	25		5		1
Enable Input Low (Note 8)	V _{EN-L}	Shutdown	-40 to 125			0.5	V
Enable Input High (Note 8)	V _{EN-H}	Enabled	-40 to 125	1.3			V
Enable Pin Input Leakage (Note 8)	I _{EN}		25		1	100	nA
Output Characteristics							
Open Loop Voltage Gain	A _{VOL}		25	120	TBD		dB
			-40 to 125	110			
			-40 to 150	90			
Output Voltage High,	V _{DD} – V _{OH}	I _{OUT} = 30 μA	25		TBD	22	mV
Referenced from V _{DD} Supply Rail			-40 to 125			50	
			-40 to 150			100	
		I _{OUT} = 3 mA	25		50		
Output Voltage Low,	V _{OL} - V _{SS}	I _{OUT} = 30 μA	25		TBD	22	mV
Referenced to V _{SS} Supply Rail			-40 to 125			90	
			-40 to 150			100	1
		I _{OUT} = 3 mA	25		50		
Short Circuit Current	I _{SC}	Sinking Current	25		30		mA
		Sourcing Current	25		30		1
Maximum Capacitive Load	C _L	No sustained oscillation	25		400		pF
Dynamic Response			•				
Bandwidth (f_3dB)	BW	C _L = 20 pF	25		1.5		MHz
Gain Margin	A _M	C _L = 20 pF	25		15		dB
Phase Margin	ФМ	C _L = 20 pF	25		60		0
Slew Rate	SR		25		0.7		V/μs
Settling Time	t _s	0.1%, A _V = 1	25		20		μS

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{8.} The enable function is available on NCS21673 only

^{9.} Shutdown Time (t_{OFF}) and Enable Time (t_{ON}) are defined as the time between the 50% point of the signal applied to the EN pin and the point at which the output voltage reaches within 10% of its final value

ELECTRICAL CHARACTERISTICS (continued)

At $T_A = +25^{\circ}C$, $V_S = 3.3$ V, and $V_{CM} = V_{OUT} = mid$ -supply, unless otherwise noted. **Boldface** limits apply over the specified temperature range, unless otherwise noted, guaranteed by characterization and/or design.

Parameter	Symbol	Conditions	Temp (°C)	Min	Тур	Max	Unit
Dynamic Response			•				
Overload Recovery Time	t _{OR}	V _{IN} * GAIN > V _S	25		200		μs
Crosstalk		f = 10 kHz	25		-100		dB
EMI Rejection Ratio	EMIRR	f = 400 MHz	25		70		dB
		f = 800 MHz	25		77		
		f = 1.8 GHz	25		91		
Noise			•				
Voltage Noise Density	e _N	f _{in} = 1 kHz	25		42		nV/√Hz
Voltage Noise, Peak-to-Peak	e _{P-P}	f _{in} = 0.1 Hz to 10 Hz	25		400		nV _{PP}
Current Noise Density	i _N	f _{in} = 1 kHZ	25		20		fA/√Hz
Power Supply							
Quiescent Current	ΙQ	Per channel	25		90	95	μА
			-40 to 125			125	
			-40 to 150			200	
Quiescent Current in	I _{QSD}	Per channel	25		TBD	300	nA
Shutdown (Note 8)			-40 to 125			300	
Power Up Time	t _{ON}		25		40		μs
Enable Time (Note 8, 9)	t _{EN}		25		40		μs
Shutdown Time (Note 8, 9)	t _{OFF}		25		TBD		μs
Power Supply Rejection	PSRR	V _S = 1.6 V to 5.5 V	25	115	TBD		dB
Ratio		V _S = 1.8 V to 5.5 V	-40 to 125	110			
			-40 to 150	90			

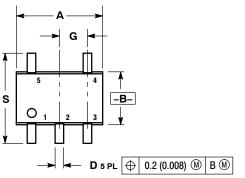
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

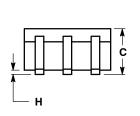
^{8.} The enable function is available on NCS21673 only

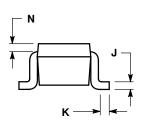
^{9.} Shutdown Time (t_{OFF}) and Enable Time (t_{ON}) are defined as the time between the 50% point of the signal applied to the EN pin and the point at which the output voltage reaches within 10% of its final value

PACKAGE DIMENSIONS

SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE L



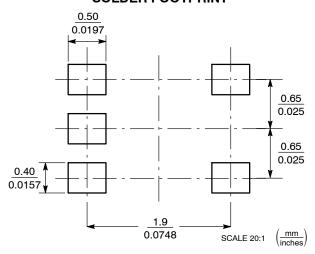




- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BLIBES BURRS.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026	BSC	0.65 BSC	
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20	REF
S	0.079	0.087	2.00	2.20

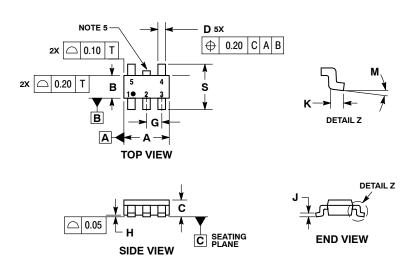
SOLDER FOOTPRINT



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

TSOP-5 **CASE 483** ISSUE M



NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

 2. CONTROLLING DIMENSION: MILLIMETERS.

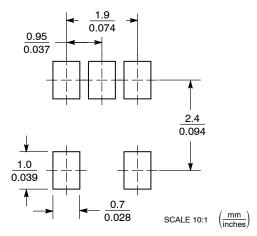
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION A.

 5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED I FAD IS ALL OVER 11 THIS I OCATION
- TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2

	MILLIMETERS				
DIM	MIN	MAX			
Α	2.85	3.15			
В	1.35	1.65			
С	0.90	1.10			
D	0.25	0.50			
G	0.95	BSC			
Н	0.01	0.10			
J	0.10	0.26			
K	0.20	0.60			
М	0°	10 °			
S	2 50	3.00			

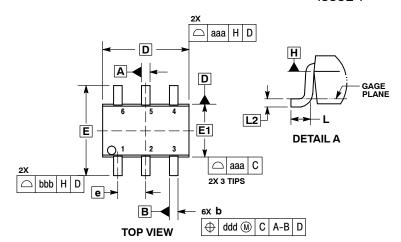
SOLDERING FOOTPRINT*

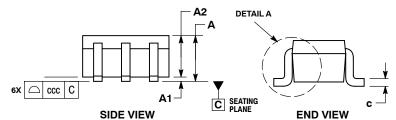


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363 CASE 419B-02 **ISSUE Y**



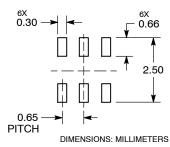


- ITES:
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END.
 DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AND DATUM H.
 DATUMS A AND B ARE DETERMINED AT DATUM H.
 DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TILL DIMENSIONS BOOK NOT INCLUDE DAMBAR PROTRUSION

- DIMENSION 6 DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION 6 AT MAXIMUM MATERIAL CONDITION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER

	MIL	LIMETE	RS	INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α			1.10			0.043
A1	0.00		0.10	0.000		0.004
A2	0.70	0.90	1.00	0.027	0.035	0.039
b	0.15	0.20	0.25	0.006	0.008	0.010
С	0.08	0.15	0.22	0.003	0.006	0.009
D	1.80	2.00	2.20	0.070	0.078	0.086
E	2.00	2.10	2.20	0.078	0.082	0.086
E1	1.15	1.25	1.35	0.045	0.049	0.053
е	0.65 BSC			0	.026 BS	С
L	0.26	0.36	0.46	0.010	0.014	0.018
L2		0.15 BS	C	(0.006 BS	SC
aaa	0.15				0.006	
bbb	0.30				0.012	
ccc	0.10				0.004	
ddd		0.10			0.004	

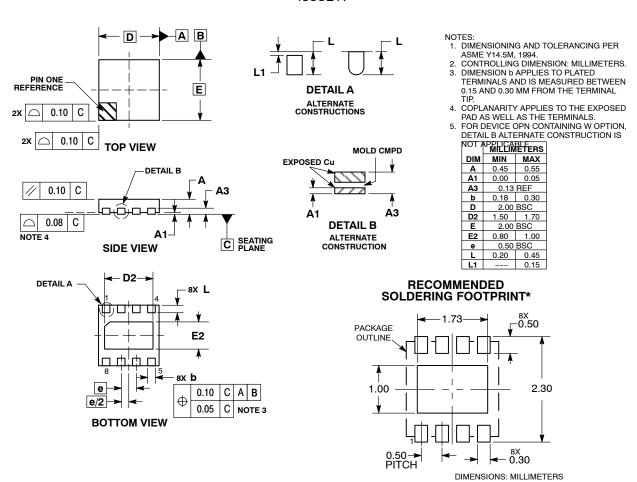
RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

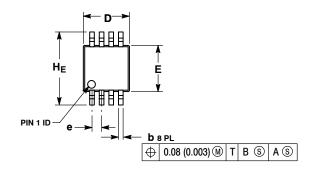
UDFN8, 2x2 CASE 517AW ISSUE A

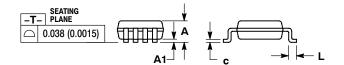


^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

Micro8™ CASE 846A-02 **ISSUE J**

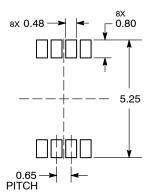




- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE. 3. DIMENSION A DUES NOT INCLUDE MOLLO FLASH, PHOTHUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.06) PER SIDE.
 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
 5. 846A-01 OBSOLETE, NEW STANDARD 846A-02.

_						
	М	MILLIMETERS INCHES				
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α			1.10			0.043
A1	0.05	0.08	0.15	0.002	0.003	0.006
b	0.25	0.33	0.40	0.010	0.013	0.016
С	0.13	0.18	0.23	0.005	0.007	0.009
D	2.90	3.00	3.10	0.114	0.118	0.122
E	2.90	3.00	3.10	0.114	0.118	0.122
е	0.65 BSC				0.026 BSC)
L	0.40	0.55	0.70	0.016	0.021	0.028
HE	4.75	4.90	5.05	0.187	0.193	0.199

RECOMMENDED SOLDERING FOOTPRINT*

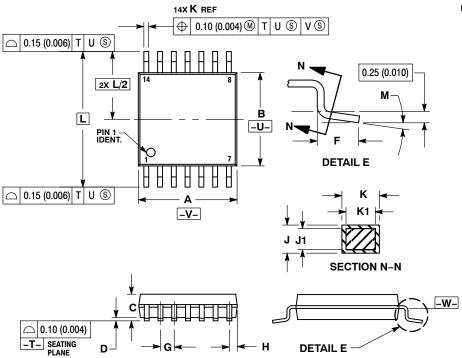


DIMENSION: MILLIMETERS

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

TSSOP-14 WB CASE 948G **ISSUE C**



NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT TYCED ALS (DOES DEED SIDE
- MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

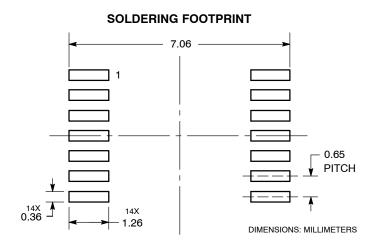
 DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

 DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.

 TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- REFERENCE ONLY.

 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65	BSC	0.026 BSC	
Н	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40		0.252 BSC	
М	0°	8 °	0°	8 °



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